

THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: **§** Patent No.: 7037857 B2
VAN GOMPEL, TONI D., et al. **§**
§ Issue Date: 05-02-2006
Application No.: 10/737115 **§**
§ Examiner: Scott Geyer
Filed: 12-16-2003 **§**
§ Group Art Unit: 2812
Docket No.: SC13151TP **§**
§
Title: METHOD FOR ELIMINATING OF EXCESSIVE FIELD OXIDE RECESS FOR THIN SI
SOI

Certificate of Submission

I hereby certify that this correspondence is being submitted to the USPTO, Alexandria, VA.

Addressed per C.F.R. § 1.1(a) and deposited with the United States Postal Service with sufficient postage as first class mail.
 Facsimile transmitted in accordance with C.F.R. §1.6(d).
 Submitted electronically via EFS in accordance with "Legal Framework for EFS Web".

March 4, 2008
Date of Submission

Teresa Shephard
Signature

Teresa Shephard
Printed Name of Person Signing Certificate

Commissioner for Patents
Alexandria, VA 22313

SUBMISSION OF CERTIFICATE OF CORRECTION

Dear Commissioner:

Enclosed is a Certificate of Correction listing error(s) in the subject patent. Please enter these corrections. Since the errors appear to be on the part of the United States Patent Office, there should be no charge.

3/3/08
Date

Respectfully submitted,

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CERTIFICATE OF CORRECTION**

Page 1 of 1

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APPLICATION NO: 10/737115

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FIRST NAMED INVENTOR: VAN GOMPEL, TONI D.

It is certified that error appears in the above-identified patent and that said Letters Patent are hereby corrected as shown below:

In Column 8, Line 51, Claim No. 18:

Change "further comprises suicide" to --further comprises silicide--

MAILING ADDRESS OF SENDER (Please do not use customer number below)

Freescale Semiconductor, Inc.

Law Department

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